Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Materi Metal	
Overall Length:	
0.210 inches	
Terminal Length	1.
0.500 inches	_
Overall Diamete	r:
0.230 inches	Device Francisco October October Devices Continue
	Device Engineering Council/jedec/case Outline Designation:
To-71	
	ne And Quantity:
2 transistor	
Mounting Metho	od:
Terminal	
Terminal Circle	Diameter:
0.100 inches	
Features Provid	
Hermetically seal	
Semiconductor	
Silicon all transist	
	n Volts Per Characteristic:
	e voltage all transistor and 50.0 drain to source voltage all transistor and 50.0 gate to source voltage all transis
•	Per Characteristic:
	es forward current, total rms megawatts all transistor
-	er Characteristic:
	mall-signal input power, common-collector absolute all transistor
•	ating Tempurature Per Measurement Point:
200.0 degrees ce	elsius junction
Special Features	5:
All transistor junc	tion pattern arrangement: npn
Terminal Type A	and Quantity:
6 uninsulated wir	e lead
Shelf Life:	
N/a	
Unit Of Measure	n:
Demilitarization	
No	
Fiig:	
A110a0	